

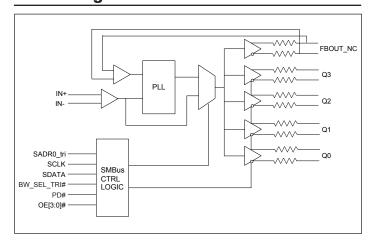


Low-Power 4-Output ZDB / Fanout Clock Buffer for PCle 6.0 and UPI

Description

The DIODES PI6CBE33045 is a low-power PCIe* 1.0/2.0/3.0/4.0/5.0/6.0 clock buffer. It takes a reference input to fanout four 100MHz low-power differential HCSL outputs with on-chip terminations for 85Ω output impedance. It supports both zero-delay and fanout buffer functions for various applications. An individual OE pin for each output provides easier power management. It uses Diodes proprietary PLL design to achieve very-low jitter that meets PCIe 1.0/2.0/3.0/4.0/5.0/6.0 requirements.

Block Diagram



Features

- Four Differential Low-Power HCSL Outputs with On-Chip Termination
- Default $Z_{OUT} = 85\Omega$
- Spread Spectrum Tolerant
- Individual Output Enable
- Selectable PLL Bandwidths
- Hardware/SMBus Control of ZDB and Fanout Buffer Modes
- 1-400MHz Fanout Buffer Operation
- Differential Output-to-output Skew <50ps
- Very Low Jitter Outputs
 - Differential Cycle-to-cycle Jitter <50ps
 - Fanout Buffer Mode Additive Phase Jitter:
 - PCIe 6.0 CC: 0.012 ps
 - DB2000Q Additive Jitter: 0.02ps
 - ZDB Mode Phase Jitter:
 - PCIe 6.0 CC: RMS 0.01 ps
 - QPI/UPI 11.4GB/s: 0.14ps RMS
 - IF-UPI: RMS 0.15 ps
- Core Supply Voltage: 3.3V
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/104/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact</u> <u>us</u> or your local Diodes representative.

https://www.diodes.com/quality/product-definitions/

- Packaging (Pb-free & Green):
 - □ 32-pin, 5mm × 5mm TQFN (ZH)

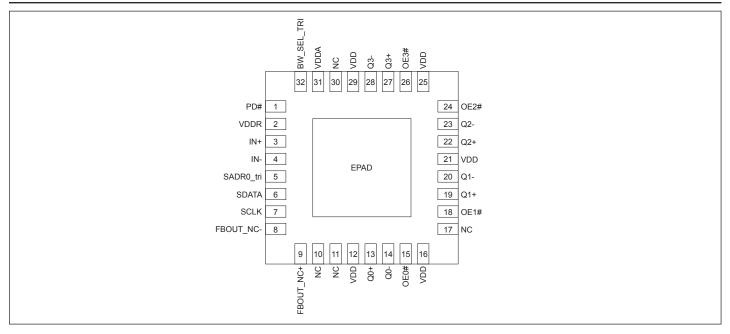
Notes

- $1.\ No\ purposely\ added\ lead.\ Fully\ EU\ Directive\ 2002/95/EC\ (RoHS),\ 2011/65/EU\ (RoHS\ 2)\ \&\ 2015/863/EU\ (RoHS\ 3)\ compliant.$
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.





Pin Configuration



Pin Description

| Pin Number | Pin Name | Type | | Description |
|-----------------------|-------------------|------------------|-----------|--|
| 1 | PD# | Input | CMOS | Input notifies device to sample latched inputs and start up on first high assertion. Low enters Power Down Mode; subsequent high assertions exit Power Down Mode. This pin has internal pullup resistor. |
| 2 | VDDR | Power | _ | Analog VDD for receiver |
| 3 | IN+ | Input | HCSL | Differential true clock input |
| 4 | IN- | Input | HCSL | Differential complementary clock input |
| 5 | SADR0_tri | Input | Tri-level | Latch to select SMBus Address. This pin has an internal pulldown. |
| 6 | SDATA | Input/ Output | CMOS | SMBUS Data line, 3.3V tolerant |
| 7 | SCLK | Input | CMOS | SMBUS clock input, 3.3V tolerant |
| 8 | FBOUT_NC- | _ | _ | Complementary differential feedback output. This pin should NOT be connected to anything outside the chip. It exists to provide delay path matching to get zero propagation delay. |
| 9 | FBOUT_NC+ | _ | _ | True differential feedback output. This pin should NOT be connected to anything outside the chip. It exists to provide delay path matching to get zero propagation delay. |
| 10, 11, 17, 30 | NC | _ | _ | Do not connect this pin. |
| 12, 16, 21, 25, 29 | V_{DD} | Power | _ | Power supply, nominal 3.3V |
| 13 | Q0+ | Output | HCSL | Differential true clock output |
| 14 | Q0- | Output | HCSL | Differential complementary clock output |





| Pin Number | Pin Name | Ту | pe | Description |
|------------|------------|--------|-----------|--|
| 15 | OE0# | Input | CMOS | Active low input for enabling Q0 pair. This pin has an internal pulldown. $1 = \text{disable outputs}$, $0 = \text{enable outputs}$ |
| 18 | OE1# | Input | CMOS | Active low input for enabling Q1 pair. This pin has an internal pulldown. $1 = disable$ outputs, $0 = enable$ outputs |
| 19 | Q1+ | Output | HCSL | Differential true clock output |
| 20 | Q1- | Output | HCSL | Differential complementary clock output |
| 22 | Q2+ | Output | HCSL | Differential true clock output |
| 23 | Q2- | Output | HCSL | Differential complementary clock output |
| 24 | OE2# | Input | CMOS | Active low input for enabling Q2 pair. This pin has an internal pulldown. $1 = \text{disable outputs}$, $0 = \text{enable outputs}$ |
| 26 | OE3# | Input | CMOS | Active low input for enabling Q3 pair. This pin has an internal pulldown. $1 = \text{disable outputs}$, $0 = \text{enable outputs}$ |
| 27 | Q3+ | Output | HCSL | Differential true clock output |
| 28 | Q3- | Output | HCSL | Differential complementary clock output |
| 31 | VDDA | Power | _ | Analog VDD |
| 32 | BW_SEL_TRI | Input | Tri-level | Latch to select low-loop bandwidth, bypass PLL, and high-loop bandwidth. This pin has internal pullup resistor |
| EPAD | EPAD | Power | _ | Connect to ground |





Power Management Table

| PD# | IN | SMBus OE bit | OEn# | Qn+ | Qn- | PLL Status |
|-----|---------|--------------|------|---------|---------|-------------------|
| 0 | X | X | X | Low | Low | Off |
| 1 | Running | 0 | X | Low | Low | On ⁽¹⁾ |
| 1 | Running | 1 | 0 | Running | Running | On ⁽¹⁾ |
| 1 | Running | 1 | 1 | Low | Low | On ⁽¹⁾ |

Note:

PLL Operating Mode Select Table

| BW_SEL_TRI | Operating Mode | PLL |
|------------|-------------------------|---------|
| 0 | PLL with Low Bandwidth | Running |
| M | PLL Bypass | Off |
| 1 | PLL with High Bandwidth | Running |

^{1.} If PLL Bypass mode is selected, the PLL will be off and outputs will be running.





Maximum Ratings

(Above which useful life may be impaired. For user guidelines, not tested.)

| Storage Temperature -65°C to $+150^{\circ}\text{C}$ | 65°C to +1 | l50°C |
|---|--------------|--------|
| Supply Voltage to Ground Potential, V_{DDxx} 0.5V to +4.6V | 0.5V to | ⊦4.6V |
| Input Voltage $-0.5V$ to $V_{DD} + 0.5V$, not exceed 4.6V | , not exceed | 4.6V |
| SMBus, Input High Voltage | | . 3.6V |
| ESD Protection (HBM)2000 V | 20 | 000 V |
| Junction Temperature125°C max | 125° | C max |

Note:

Stresses greater than those listed under MAXIMUM RAT-INGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

Operating Conditions

Temperature = T_A; Supply voltages per normal operation conditions; See test circuits for the load conditions

| Symbol | Parameters | Conditions | Min. | Тур. | Max. | Units |
|----------------------------|--|---|-------|------|-------|-------|
| V_{DD}, V_{DDA}, V_{DDR} | Power Supply Voltage | _ | 3.135 | 3.3 | 3.465 | V |
| I_{DDA} | Analog Power Supply Current | V_{DDA} , PLL mode, All outputs active @ 100MHz | _ | 21 | 25 | mA |
| I_{DD} | Power Supply Current | $V_{\rm DD}$ + $V_{\rm DD_R}$, All outputs active @ 100MHz | _ | 70 | 85 | mA |
| $I_{\mathrm{DDA_PD}}$ | Analog Power Supply Power Down ⁽¹⁾ Current | V _{DDA} , PLL mode, All outputs LOW/LOW | _ | 0.6 | 1 | mA |
| I _{DD_PD} | Power Supply Power Down ⁽¹⁾ Current | V_{DD} + $V_{\mathrm{DD_R}}$, All outputs LOW/LOW | _ | 2.5 | 3 | mA |
| T_{A} | Ambient Temperature | Industrial grade | -40 | _ | 85 | °C |

Note:

- 1. Input clock is not running.
- 2. Outputs drive 5 inch trace.

Input Electrical Characteristics

| Symbol | Parameters | Conditions | Min. | Тур. | Max. | Units |
|------------------|------------------------------|------------|------|------|------|-------|
| R _{pu} | Internal Pullup Resistance | _ | _ | 120 | _ | ΚΩ |
| R _{dn} | Internal Pulldown Resistance | _ | _ | 120 | _ | ΚΩ |
| L _{PIN} | Pin Inductance | _ | _ | _ | 7 | nН |





SMBus Electrical Characteristics

Temperature = T_A ; Supply voltages per normal operation conditions; See test circuits for the load conditions

| Symbol | Parameters | Conditions | Min. | Тур. | Max. | Units |
|----------------------|---------------------------|--|-----------------------------|------|------|-------|
| V _{DDSMB} | Nominal Bus Voltage | _ | 2.7 | _ | 3.6 | V |
| | | SMBus, $V_{DDSMB} = 3.3V$ | 2.1 | _ | 3.6 | |
| V _{IHSMB} S | SMBus Input High Voltage | SMBus, $V_{DDSMB} < 3.3V$ | 0.65* V _{DDSMB} | _ | _ | V |
| 37 | SMBus Input Low Voltage | SMBus, $V_{DDSMB} = 3.3V$ | _ | _ | 0.8 | V |
| V _{ILSMB} | | SMBus, V _{DDSMB} < 3.3V | _ | _ | 0.8 | V |
| I _{SMBSINK} | SMBus Sink Current | SMBus, at V _{OLSMB} | 4 | _ | _ | mA |
| V _{OLSMB} | SMBus Output Low Voltage | SMBus, at I _{SMBSINK} | _ | _ | 0.4 | V |
| f_{MAXSMB} | SMBus Operating Frequency | Maximum frequency | _ | _ | 500 | kHz |
| t _{RMSB} | SMBus Rise Time | (Max V_{IL} - 0.15) to (Min V_{IH} + 0.15) | _ | _ | 1000 | ns |
| t _{FMSB} | SMBus Fall Time | (Min V_{IH} + 0.15) to (Max V_{IL} - 0.15) | _ | _ | 300 | ns |

LVCMOS DC Electrical Characteristics

Temperature = T_A; Supply voltages per normal operation conditions; See test circuits for the load conditions

| Symbol | Parameters | Conditions | Min. | Тур. | Max. | Units |
|-------------------|--------------------|--|------------------------------|------------------------------|------------------------------|-------|
| V_{IH} | Input High Voltage | Single-ended inputs, except SMBus | 0.75* V _{DD} | _ | V _{DD} +0.3 | V |
| V_{IM} | Input Mid Voltage | SADR0_TRI, SADR1_TRI, BW_SEL_TRI | $0.4 \mathrm{V}_\mathrm{DD}$ | $0.5 \mathrm{V}_\mathrm{DD}$ | $0.6 \mathrm{V}_\mathrm{DD}$ | V |
| $V_{\rm IL}$ | Input Low Voltage | Single-ended inputs, except SMBus | -0.3 | _ | 0.25 V _{DD} | V |
| I_{IH} | Input High Current | Single-ended inputs, $V_{IN} = V_{DD}$ | _ | _ | 5 | μΑ |
| I_{IL} | Input Low Current | Single-ended inputs, $V_{\rm IN}$ = 0V | -5 | _ | _ | μΑ |
| I_{IH} | Input High Current | Single-ended inputs with pullup/pulldown resistor, $V_{\mathrm{IN}} = V_{\mathrm{DD}}$ | _ | _ | 50 | μΑ |
| I_{IL} | Input Low Current | Single-ended inputs with pullup/pulldown resistor, $V_{\mathrm{IN}} = 0 \mathrm{V}$ | -50 | _ | _ | μΑ |
| C _{IN} | Input Capacitance | _ | 1.5 | _ | 5 | pF |

LVCMOS AC Electrical Characteristics

Temperature = T_A; Supply voltages per normal operation conditions; See test circuits for the load conditions

| Symbol | Parameters | Conditions | Min. | Тур. | Max. | Units |
|--------------------|-----------------------|---|------|------|------|--------|
| t _{OELAT} | Output Enable Latency | Q start after OE# assertion Q stop after OE# deassertion | 4 | 5 | 10 | clocks |
| t _{PDLAT} | PD# Deassertion | Differential outputs enable after PD# deassertion | _ | 20 | 300 | μs |





HCSL Input Characteristics(1)

Temperature = TA; Supply voltages per normal operation conditions; See test circuits for the load conditions

| Symbol | Parameters | Conditions | Min. | Тур. | Max. | Units |
|-----------------------------|---|--|------|------|-------|-------|
| V _{IHDIF} | Diff. Input High Voltage ⁽³⁾ | IN+, IN-, single-end measurement | 600 | 800 | 1150 | mV |
| V_{ILDIF} | Diff. Input Low Voltage ⁽³⁾ | IN+, IN-, single-end measurement | -300 | 0 | 300 | mV |
| V _{COM} | Diff. Input Common Mode Voltage | _ | 150 | | 900 | mV |
| V _{SWING} | Diff. Input Swing Voltage | Peak to peak value (V _{IHDIF} - V _{ILDIF)} | 300 | _ | 2900 | mV |
| f_{INBP} | Input Frequency | PLL Bypass mode | 1 | _ | 400 | MHz |
| f _{IN100} | Input Frequency | 100MHz PLL | 98.5 | 100 | 102.5 | MHz |
| f _{MODI} - PCIe | Input SS Modulation Freq. PCIe | Allowable frequency for PCIe applications (Triangular Modulation) | 30 | _ | 33 | kHz |
| t _{STAB} | Clock stabilization | From V_{DD} Power-Up and after input clock stabilization or de-assertion of PD# to 1st clock | _ | 0.75 | 1.0 | ms |
| t_{RF} | Diff. Input Slew Rate ⁽²⁾ | Measured differentially with 10 inch trace. Please refer to test load Figure 1. | 0.4 | _ | _ | V/ns |
| I _{IN} | Diff. Input Leakage Current | $V_{IN} = V_{DD}, V_{IN} = GND$ | -5 | 0.01 | 5 | uA |
| t_{DC} | Diff. Input Duty Cycle | Measured differentially | 45 | _ | 55 | % |
| tj _{c-c} | Diff. Input Cycle to cycle jitter | Measured differentially | _ | _ | 125 | ps |

Note:

- 1. Guaranteed by design and characterization, not 100% tested in production
- 2. Slew rate measured through +/-75mV window centered around differential zero
- 3. The device can be driven by a single-ended clock by driving the true clock and biasing the complement clock input to the Vbias, where Vbias is $(V_{IH}-V_{IL})/2$

HCSL Output DC Characteristics

Temperature = T_A; Supply voltages per normal operation conditions; See test circuits for the load conditions

| Symbol | Parameters | Condition | Min. | Тур. | Max. | Units |
|-------------------|---|--|------|------|------|-------|
| V _{OH} | Output Voltage High ⁽¹⁾ | Statistical measurement on single-ended | 660 | _ | 850 | mV |
| V _{OL} | Output Voltage Low ⁽¹⁾ | signal using oscilloscope math function | -150 | _ | 150 | mV |
| V _{OMAX} | Output Voltage Maximum ⁽¹⁾ | Measurement on single ended signal using | _ | _ | 1150 | mV |
| V _{OMIN} | Output Voltage Minimum ⁽¹⁾ | absolute value | -300 | _ | _ | mV |
| V _{OC} | Output Cross Voltage ^(1,2,4) | _ | 250 | _ | 550 | mV |
| DV _{OC} | V _{OC} Magnitude Change ^(1,2,5) | _ | _ | _ | 140 | mV |

- 1. At default SMBUS amplitude settings.
- 2. Guaranteed by design and characterization—not 100% tested in production.
- 3. Measured from differential waveform.
- 4. This one is defined as voltage where Q+=Q- measured on a component test board and only applied to the differential rising edge.
- 5. The total variation of all Vcross measurements in any particular system. This is a subset of Vcross_min/max allowed.





HCSL Output AC Characteristics

Temperature = T_A; Supply voltages per normal operation conditions; See test circuits for the load conditions

| Symbol | Parameters | Condition | Min. | Тур. | Max. | Units |
|-----------------------------|--|---|------|------|-------|-------|
| C | 0.4.45 | PLL mode 100MHz | 98.5 | 100 | 102.5 | MHz |
| f_{OUT} | Output Frequency | PLL bypass mode | 1 | _ | 400 | MHz |
| BW | PLL Bandwidth ^(1,8) | -3dB point in High Bandwidth Mode | 2 | 2.65 | 4 | MHz |
| DVV | PLL bandwidth *** | -3dB point in Low Bandwidth Mode | 0.7 | 1.1 | 1.4 | MHz |
| 4: | DI I litton Doolein a | Peak pass band gain, low bandwidth | 0 | 1.2 | 2 | dB |
| tj _{peak} | PLL Jitter Peaking | Peak pass band gain, high bandwidth | 0 | 1.2 | 2.5 | dB |
| t_{RF} | Slew Rate ^(1,2,3) | Scope averaging on fast setting with 10 inch trace. Please refer to test load Figure 1. | 2.2 | 3 | 4.0 | V/ns |
| $\mathrm{Dt}_{\mathrm{RF}}$ | Slew Rate Matching ^(1,2,4) | Scope averaging on | _ | 8 | 20 | % |
| t _{SKEW} | Output Skew ^(1,2) | Averaging on, $V_T = 50\%$ | _ | 30 | 50 | ps |
| t_{DC} | Duty Cycle ^(1,2) | Measured differentially, PLL Mode | 45 | 50 | 55 | % |
| t _{DCD} | Duty Cycle Distortion ^(1,7) | Measured differentially, PLL Bypass Mode at 100MHz | -3.5 | 0 | 3.5 | % |
| 4: | C1- 4- C1- I:44(1.2) | PLL mode | _ | 14 | 50 | ps |
| tj _{c-c} | Cycle-to-Cycle Jitter ^(1,2) | Additive jitter, Bypass mode | _ | 0.1 | 1 | ps |
| t _{pd_PLL} | Propagation delay | Input to output propagation delay in PLL mode at 100MHz with nominal temperature and voltage | -100 | 15 | 100 | ps |
| t _{pd_BYP} | Propagation delay | Input to output propagation delay in ByPass mode at 100MHz with nominal temperature and voltage | 1650 | 2150 | 2650 | ps |





HCSL Output AC Characteristics (PLL Mode PCIe Phase Jitter)

| Symbol | Parameters | Condition | Min. | Тур. | Max. | Spec Limit | Units |
|-----------------------------|---|--------------------------|------|-------|-------|---------------|----------|
| | | PCIe 1.0 ⁽⁶⁾ | _ | 2.5 | 5 | 86 | ps (p-p) |
| | | PCIe 2.0 Low Band | _ | 0.025 | 0.05 | 3.1 | ps |
| | Integrated Phase Jitter PLL Mode (RMS) ^(1,5) | PCIe 2.0 High Band | _ | 0.161 | 0.18 | 3 | ps |
| tj _{PH_PLL_} CC | Low Bandwidth (Common | PCIe 3.0 | _ | 0.051 | 0.071 | 1 | ps |
| CC | Clocked Architecture) | PCIe 4.0 | _ | 0.051 | 0.071 | 0.5 | ps |
| | , | PCIe 5.0 ⁽¹¹⁾ | _ | 0.013 | 0.022 | 0.15 | ps |
| | | PCIe 6.0 | _ | 0.01 | 0.016 | 0.1 | ps |
| | | PCIe 1.0 | _ | 7.8 | 8.7 | _ | ps (p-p) |
| | Integrated Phase Jitter PLL | PCIe 2.0 | _ | 0.139 | 0.208 | _ | ps |
| tj _{PH_PLL_} | Mode (RMS) ^(1,5) | PCIe 3.0 | _ | 0.061 | 0.12 | _ | ps |
| SRIS | Low Bandwidth (SRIS | PCIe 4.0 | _ | 0.062 | 0.12 | _ | ps |
| | Architecture) | PCIe 5.0 ⁽¹¹⁾ | _ | 0.062 | 0.105 | _ | ps |
| | | PCIe 6.0 | _ | 0.05 | 0.085 | _ | ps |
| | | PCIe 1.0 ⁽⁶⁾ | _ | 5.1 | 6.5 | 86 | ps (p-p) |
| | | PCIe 2.0 Low Band | _ | 0.026 | 0.052 | 3.1 | ps |
| | Integrated Phase Jitter PLL | PCIe 2.0 High Band | _ | 0.18 | 0.24 | 3 | ps |
| tj _{PH_PLL_} CC | Mode (RMS) ^(1,5) High Bandwidth (Com- | PCIe 3.0 | _ | 0.053 | 0.063 | 1 | ps |
| CC | mon Clocked Architecture) | PCIe 4.0 | _ | 0.053 | 0.063 | 0.5 | ps |
| | , | PCIe 5.0 ⁽¹¹⁾ | _ | 0.016 | 0.027 | 0.15 | ps |
| | | PCIe 6.0 | _ | 0.012 | 0.02 | 0.1 | ps |
| | | PCIe 1.0 | _ | 7.51 | 8.12 | _ | ps (p-p) |
| | Integrated Phase Jitter PLL | PCIe 2.0 | _ | 0.153 | 0.198 | _ | ps |
| tj _{PH_PLL_} | Mode (RMS) ^(1,5) | PCIe 3.0 | _ | 0.067 | 0.087 | _ | ps |
| SRIS | High Bandwidth (SRIS | PCIe 4.0 | _ | 0.07 | 0.09 | _ | ps |
| | Architecture) | PCIe 5.0 ⁽¹¹⁾ | _ | 0.065 | 0.111 | _ | ps |
| | | PCIe 6.0 | _ | 0.056 | 0.095 | _ | ps |

- 1. Guaranteed by design and characterization—not 100% tested in production.
- 2. Measured from differential waveform.
- 3. Slew rate is measured through the Vswing voltage range centered around differential 0V, within $\pm 150 \text{mV}$ window.
- 4. Slew rate matching is measured through $\pm 75 \text{mV}$ window centered around differential zero.
- 5. See http://www.pcisig.com for complete specs.
- Sample size of at least 100k cycles. This can be extrapolated to 108ps pk-pk@ 1M cycles for a BER of 10⁻¹².
- 7. Duty cycle distortion is the difference in duty cycle between the output and input clock when the device is operated in the PLL bypass mode.
- 8. The Min and Max values of each BW setting track each other, low BW max will never occur with high BW min.
- 9. Applies to all differential outputs.
- 10. For additive jitter RMS value is calculated by the following equation = SQRT [(total jitter)* 2 (input jitter)* 2].
- 11. PCIe 5.0 v0.9 specification.





HCSL Output AC Characteristics (Fanout Buffer Mode Additive Phase Jitter)

| Symbol | Parameters | Condition | Min. | Тур. | Max. | Output Limit | Units |
|--------------------------------|---|--------------------------|------|-------|--------|-----------------|----------|
| | | PCIe 1.0 ⁽⁶⁾ | _ | 1.2 | 1.8 | 86 | ps (p-p) |
| | | PCIe 2.0 Low Band | _ | 0.004 | 0.015 | 3 | ps |
| | (RMS) ^(1,5) (Common Clocked Architec- | PCIe 2.0 High Band | _ | 0.058 | 0.087 | 3.1 | ps |
| tj _{PH_A_CC} | | PCIe 3.0 | _ | 0.019 | 0.0228 | 1 | ps |
| | | PCIe 4.0 | _ | 0.019 | 0.0228 | 0.5 | ps |
| | , | PCIe 5.0 ⁽¹¹⁾ | _ | 0.014 | 0.024 | 0.15 | ps |
| | | PCIe 6.0 | _ | 0.012 | 0.020 | 0.10 | ps |
| | | PCIe 1.0 | _ | 0.111 | 0.154 | _ | ps (p-p) |
| | | PCIe 2.0 | _ | 0.051 | 0.09 | _ | ps |
| | Additive Integrated Phase Jitter (RMS) ^(1,5,10) | PCIe 3.0 | _ | 0.022 | 0.042 | _ | ps |
| tj _{PH_A_SRIS} | (SRIS Architecture) | PCIe 4.0 | _ | 0.023 | 0.043 | _ | ps |
| | (ORIO Michitecture) | PCIe 5.0 ⁽¹¹⁾ | _ | 0.024 | 0.041 | _ | ps |
| | | PCIe 6.0 | _ | 0.022 | 0.037 | _ | ps |
| tj _{PH_A_12k-} 20M | Additive Integrated Phase Jitter $(RMS)^{(1,5,10)}$ 12kHz ~ 20MHz | 100MHz, SSC off | _ | 0.086 | 0.111 | _ | ps |

- $1. \quad Guaranteed \ by \ design \ and \ characterization-not \ 100\% \ tested \ in \ production.$
- 2. Measured from differential waveform.
- 3. Slew rate is measured through the Vswing voltage range centered around differential 0V, within ±150mV window.
- 4. Slew rate matching is measured through ± 75 mV window centered around differential zero.
- 5. See http://www.pcisig.com for complete specs.
- 6. Sample size of at least 100k cycles. This can be extrapolated to 108ps pk-pk @ 1M cycles for a BER of 10⁻¹².
- 7. Duty cycle distortion is the difference in duty cycle between the output and input clock when the device is operated in the PLL bypass mode.
- 8. The Min and Max values of each BW setting track each other, low BW max will never occur with high BW min.
- 9. Applies to all differential outputs.
- 10. For additive jitter RMS value is calculated by the following equation = SQRT [(total jitter) *2 (input jitter) *2].
- 11. PCIe 5.0 v0.9 specification.





HCSL Output Filtered Phase Jitter (QPI_UPI/DB2000Q)

| Symbol | Parameters | Condition | Min. | Тур. | Max. | Spec Limit | Units |
|--------------------------------|--|--|------|------|------|---------------|----------|
| | | QPI and UPI, 100M or 133.33MHz, 4.8Gbps, 6.4Gbps 12UI | _ | 0.18 | 0.38 | 0.5 | ps |
| tj _{PHPLL} QPI_UPI | Integrated Phase Jitter PLL Mode (RMS) ^(1,5) | QPI and UPI, 100MHz, 8.0Gbps, 12UI | _ | 0.17 | 0.2 | 0.3 | ps |
| QPI_UPI | Mode (RMIO) | QPI and UPI, 100MHz, <11.4Gbps, 12UI | _ | 0.14 | 0.16 | 0.2 | ps |
| | Fanout Buffer Mode | QPI and UPI, 100M or 133.33MHz, 4.8Gbps, 6.4Gbps 12UI | _ | 0.06 | 0.08 | _ | ps (p-p) |
| tj _{PH_QPI_} UPI | Additive Integrated Phase Jitter (RMS) ^(1,5,10) | QPI and UPI, 100MHz, 8.0Gbps, 12UI | _ | 0.06 | 0.08 | _ | ps |
| UPI | | QPI and UPI, 100MHz, <11.4Gbps, 12UI | _ | 0.03 | 0.06 | _ | ps |
| | PLL Mode IF-UPI phase | Low bandwidth | _ | 0.15 | 0.18 | 1 | ps |
| tj _{PH_IFUPI} | jitter | High bandwidth | _ | 0.18 | 0.22 | 1 | ps |
| GFII_IFUFI | Fanout Buffer Mode IF- UPI phase jitter | _ | | 0.08 | 0.1 | 1 | ps |
| tj _{PH} _ DB2000Q | Fanout Buffer Mode DB2000Q phase jitter | _ | _ | 0.02 | 0.03 | 0.08 | ps |

- 1. Guaranteed by design and characterization—not 100% tested in production.
- 2. Measured from differential waveform.
- 3. Slew rate is measured through the Vswing voltage range centered around differential 0V, within ±150mV window.
- 4. Slew rate matching is measured through $\pm 75 \text{mV}$ window centered around differential zero.
- 5. See http://www.pcisig.com for complete specs.
- 6. Sample size of at least 100k cycles. This can be extrapolated to 108ps pk-pk @ 1M cycles for a BER of 10⁻¹².
- 7. Duty cycle distortion is the difference in duty cycle between the output and input clock when the device is operated in the PLL bypass mode.
- 8. The Min and Max values of each BW setting track each other, low BW max will never occur with high BW min.
- 9. Applies to all differential outputs.
- 10. For additive jitter RMS value is calculated by the following equation = SQRT [(total jitter) *2 (input jitter) *2].
- 11. PCIe 5.0 v0.9 specification.





SMBus Serial Data Interface

PI6CBE33045 is a slave-only device that supports block read and block write protocol using a single 7-bit address and read/write bit as shown below.

Read and write block transfers can be stopped after any complete byte transfer.

Address Assignment

| A6 | A5 | A4 | A3 | A2 | A1 | A0 | R/W |
|----|----|----|----|----|----|----|-----|
| 1 | 1 | 0 | 1 | 1 | 0 | 0 | 1/0 |

Note: SMBus address is latched on SADR pin

SMBus Address

|] | Pin | SMBus Address | | | | | | | | |
|-----------|-----------|-------------------------|-----|-------------|-------------|--|--|--|--|--|
| SADR1_tri | SADR0_tri | PI6CBE3312x PI6CBE3308x | | PI6CBE3306x | PI6CBE33045 | | | | | |
| 0 | 0 | D8 | D8 | D8 | D8 | | | | | |
| 0 | M | DA | N/A | N/A | DA | | | | | |
| 0 | 1 | DE | N/A | N/A | DE | | | | | |
| M | 0 | C2 | N/A | N/A | N/A | | | | | |
| M | M | C4 | N/A | N/A | N/A | | | | | |
| M | 1 | C6 | N/A | N/A | N/A | | | | | |
| 1 | 0 | CA | N/A | N/A | N/A | | | | | |
| 1 | M | CC | N/A | N/A | N/A | | | | | |
| 1 | 1 | CE | N/A | N/A | N/A | | | | | |

Note: PI6CBE3308x and PI6CBE3306x do not have SMBus address select pins. Their address is D8.

How to Write

| 1 bit | 7 bits | 1 bit | 1 bit | 8 bits | 1 bit | 8 bits | 1 bit | 8 bits | 1 bit | 8 bits | 1 bit | 1 bit |
|-----------|--------|-------|-------|-------------------------------------|-------|------------------------|-------|-------------------------|-------|--------------------------|-------|----------|
| Start bit | Add. | W(0) | Ack | Beginning Byte loca- tion = N | Ack | Data Byte count = X | Ack | Beginning Data Byte (N) | Ack | Data Byte (N+X-1) | Ack | Stop bit |

How to Read

| 1 bit | 7 bits | 1 bit | 1 bit | 8 bits | 1 bit | 1 bit | 7 bits | 1 bit | 1 bit | 8 bits | 1 bit | 8 bits | 1 bit |
|-----------|---------|-------|-------|-------------------------------------|-------|---------------------|---------|-------|-------|------------------------|-------|-------------------------|-------|
| Start bit | Address | W(0) | Ack | Beginning Byte loca- tion = N | Ack | Repeat Start bit | Address | R(1) | Ack | Data Byte count = X | Ack | Beginning Data Byte (N) | Ack |

| | 8 bits | 1 bit | 1 bit |
|-------|-----------|-------|----------|
| | Data Byte | NAck | Stop bit |
| ••••• | (N+X-1) | IVACK | Stop bit |





Byte 0: PLL Operating Mode and Frequency Select Register

| Bit | Control Function | Description | Туре | Power-up Condition | 0 | 1 |
|-----|-------------------------|---------------------------|-------------------|-----------------------|-------------------|---------------|
| 7 | PLLMODERB1 | PLL Mode Readback Bit1 | R | Latch | 00 = Low BW | ZDB |
| | | | | | 01= Fanout me | ode |
| 6 | PLLMODERB0 | PLL Mode Readback Bit0 | R | Latch | 10 = Reserved | |
| | | | | | 11 = High BW | ZDB |
| 5 | Reserved | _ | | 0 | _ | _ |
| 4 | Reserved | _ | | 0 | _ | _ |
| 3 | PLL SW Control | PLL Mode control Bit0 | RW ⁽¹⁾ | 0 | Hardware Latch | SMBus Control |
| 2 | PLL mode | PLL Mode 1 | RW | 1 | 00 = Low BW | ZDB |
| | | | | | 01= Fanout me | ode |
| 1 | PLL mode | PLL Mode 0 | RW | 1 | 10 = Reserved | |
| | | | | | 11 = High BW | ZDB |
| 0 | Frequency Select RB | Frequency select readback | R | Latch | 133MHz | 100MHz |

Byte 1: Output Enable Register 1

| Bit | Control Function | Description | Туре | Power-up Condition | 0 | 1 |
|-----|-------------------------|------------------|------|-----------------------|--------------------|-------------------|
| 7 | Reserved | | RW | 0 | | |
| 6 | Q2_OE | Q2 output enable | RW | 1 | Output Low/ Low | OE Pin Control |
| 5 | Q1_OE | Q1 output enable | RW | 1 | Output Low/ Low | OE Pin Control |
| 4 | Reserved | _ | RW | 0 | _ | _ |
| 3 | Reserved | _ | RW | 0 | _ | _ |
| 2 | Q0_OE | Q0 output enable | RW | 1 | Output Low/ Low | OE Pin Control |
| 1 | Reserved | _ | RW | 0 | _ | _ |
| 0 | Reserved | _ | RW | 0 | _ | _ |





Byte 2: Output Enable Register 2

| Bit | Control Function | Description | Туре | Power-up Condition | 0 | 1 |
|-----|------------------|------------------|------|-----------------------|--------------------|-------------------|
| 7 | Reserved | _ | RW | 0 | _ | _ |
| 6 | Reserved | _ | RW | 0 | _ | _ |
| 5 | Reserved | _ | RW | 0 | _ | _ |
| 4 | Reserved | _ | RW | 0 | _ | _ |
| 3 | Reserved | _ | RW | 0 | _ | _ |
| 2 | Reserved | _ | RW | 0 | _ | _ |
| 1 | Q3_OE | Q3 output enable | RW | 1 | Output Low/ Low | OE Pin Control |
| 0 | Reserved | _ | RW | 0 | _ | _ |

Byte 3 and Byte 4: Reserved

Byte 5: Revision and Vendor ID Register

| Bit | Control Function | Description | Туре | Power-up Condition | 0 | 1 | |
|-----|-------------------------|-------------|------|-----------------------|---------------|---|--|
| 7 | RID3 | | R | 0 | | | |
| 6 | RID2 | Revision ID | R | 0 | rev = 0000 | | |
| 5 | RID1 | | R | 0 | | | |
| 4 | RID0 | | R | 0 | | | |
| 3 | PVID3 | Vendor ID | R | 0 | Di la cont | | |
| 2 | PVID2 | | R | 0 | | | |
| 1 | PVID1 | | R | 1 | Diodes = 0011 | | |
| 0 | PVID0 | | R | 1 | | | |





Byte 6: Device ID Register

| Bit | Control Function | Description | Туре | Power-up Condition |
|-----|-------------------------|-------------|------|-----------------------|
| 7 | - NA | DID7 | R | |
| 6 | | DID6 | R | |
| 5 | | DID5 | R | |
| 4 | | DID4 | R | ol Di |
| 3 | | DID3 | R | 0hB1 |
| 2 | | DID2 | R | |
| 1 | | DID1 | R | |
| 0 | | DID0 | R | |

Byte 7: Byte Count Register

| Bit | Control Function | Description | Туре | Power-up Condition | 0 | 1 |
|-----|-------------------------|---|------|-----------------------|---|---|
| 7 | Reserved | _ | | 0 | _ | _ |
| 6 | Reserved | _ | | 0 | _ | _ |
| 5 | Reserved | _ | | 0 | _ | _ |
| 4 | BC4 | Wring to the register configures how many bytes will be read back on a block read | RW | 0 | _ | _ |
| 3 | BC3 | | RW | 1 | _ | _ |
| 2 | BC2 | | RW | 0 | _ | _ |
| 1 | BC1 | | RW | 0 | _ | _ |
| 0 | BC0 | | RW | 0 | _ | _ |





Test Loads

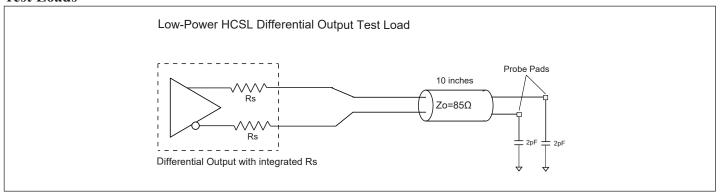


Figure 1. Low-Power HCSL Test Circuit

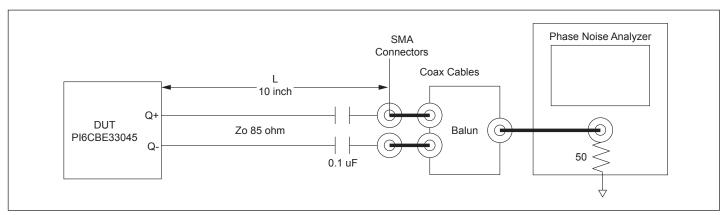


Figure 2. Test Set Up for Phase Jitter Measurement

LVDS Output Termination Table

| Component | Receiver with Termination | Receiver without Termination | Unit |
|-----------------------------------|---------------------------|------------------------------|------|
| R _{1a} , R _{1b} | 10,000 | 130 | Ω |
| R_{2a}, R_{2b} | 5600 | 64 | Ω |
| C _C | 0.1 | 0.1 | μF |
| V_{CM} | 1.2 | 1.2 | V |





LVDS Output Termination

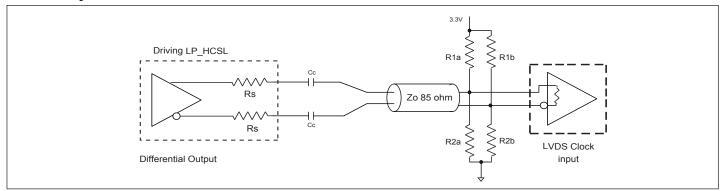


Figure 3. Differential Output Driving LVDS

Power Supply

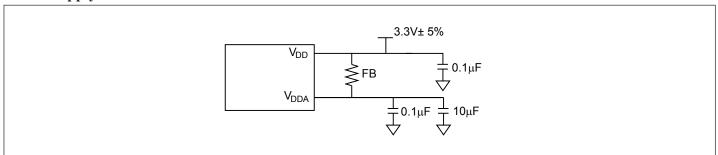
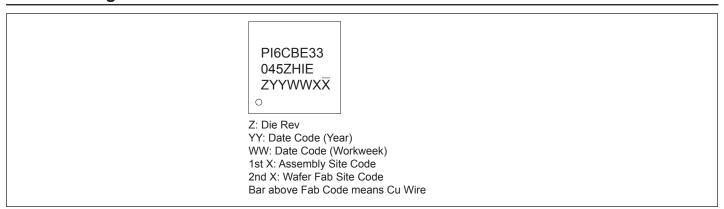


Figure 4. Power Supply Filter

Thermal Characteristics Table

| - 1101 111W1 C11W1 WVVV 11W1V | | | | | | | |
|-------------------------------|--|------------|------|------|------|------|--|
| Symbol | Parameter | Conditions | Min. | Тур. | Max. | Unit | |
| θ_{JA} | Thermal Resistance Junction to Ambient | Still air | | 34.4 | | °C/W | |
| $\theta_{ m JC}$ | Thermal Resistance Junction to Case | | | 15 | | °C/W | |

Part Marking

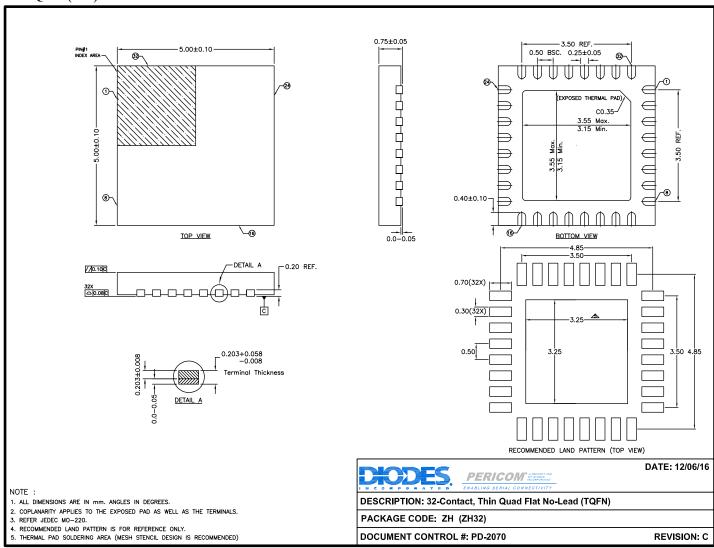






Packaging Mechanical

32-TQFN (ZH)



17-0570

For latest package information:

 $See \ http://www.diodes.com/design/support/packaging/pericom-packaging/packaging-mechanicals-and-thermal-characteristics/.$





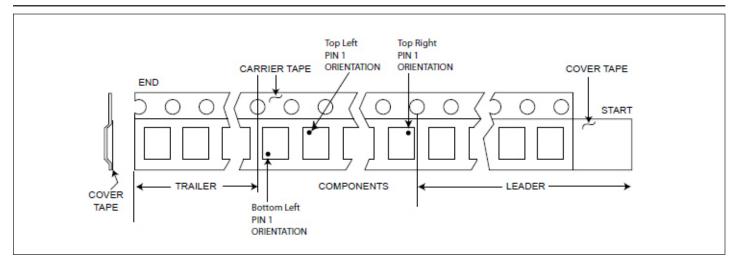
Ordering Information

| Ordering Code | Package Code | Package Description | Temperature | Pin 1 Orientation | |
|----------------------|-----------------|---|-------------|----------------------|--|
| PI6CBE33045ZHIEX | ZH | 32-Contact, Thin Quad Flat No-Lead (TQFN) | -40~85°C | Top Right Corner | |
| PI6CBE33045ZHIEX-13R | ZH | 32-Contact, Thin Quad Flat No-Lead (TQFN) | -40~85°C | Top Left Corner | |

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- $2. \ See \ https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.$
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. I = Industrial
- 5. E = Pb-free and Green
- 6. X suffix = Tape/Reel
- 7. For packaging detail, go to our website at: https://www.diodes.com/assets/MediaList-Attachments/Diodes-Package-Information.pdf

Pin 1 Orientation







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RC19020A072GN2#BB0 RC19016AGN1#BB0 RC19216AGN6#BD0 RC19016A100GN1#BB0 RC19013A100GNG#BB0
PI6C4911502DZHIEX 9FGL0651DKILF 9FGL0641DKILF RC19204AGNL#BB0 RC19202AGNT#BD0 MC100EP11DR2G Si53301-B-GMR SI5330C-B00209-GM NB3RL02FCT2G SY75578LMG